CMOS Digital Integrated Circuits Silicon Monolithic

74VHCV240FT,74VHCV244FT

1. Functional Description

Octal Schmitt Bus Buffer
74VHCV240FT: Inverted, 3-State Outputs
74VHCV244FT: Non-Inverted, 3-State Outputs

2. General

The 74VHCV240FT and 74VHCV244FT are advanced high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate C^2MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The 74VHCV240FT is an inverting 3-state buffer having two active-low output enables. The 74VHCV244FT is a non-inverting 3-state buffer, and has two active-low output enables.

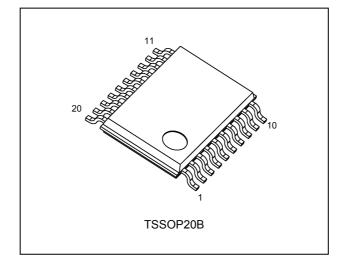
These devices are designed to be used with 3-state memory address drivers, etc.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

3. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range: $T_{opr} = -40$ to 125 °C
- (3) High speed: $t_{pd} = 3.9$ ns (typ.) at $V_{CC} = 5.0$ V
- (4) Low power dissipation: $I_{CC} = 2.0 \ \mu A \ (max)$ at $T_a = 25 \ ^{\circ}C$
- (5) Wide operating voltage range: $V_{CC(opr)} = 1.8 \text{ V to } 5.5 \text{ V}$
- (6) Output current: $|I_{OH}|/I_{OL} = 16 \text{ mA} (\min)(V_{CC} = 4.5 \text{ V})$
- (7) Power-down protection provided on all inputs.
- (8) Pin and function compatible with the 74 series (74AC/HC/AHC/LV etc.) 240 or 244 type.
- Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

4. Packaging

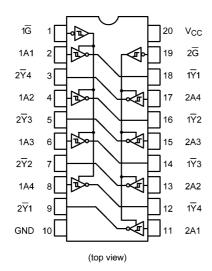


Start of commercial production 2014-07 2016-08-04 Rev.2.0

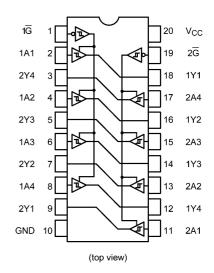
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5. Pin Assignment

74VHCV240FT

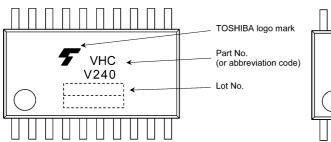


74VHCV244FT

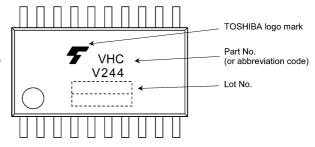


6. Marking

74VHCV240FT



74VHCV244FT



7. Truth Table

Input G	Input An	Output Yn	Output Yn
L	L	L	Н
L	Н	Н	L
Н	Х	Z	Z

X: Don't care

Z: High impedance

Yn: 74VHCV244FT

Yn: 74VHCV240FT

8. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to 7.0	V
Output voltage	V _{OUT}	(Note 1)	-0.5 to 7.0	V
		(Note 2)	-0.5 to V _{CC} + 0.5	
Input diode current	I _{IK}		-50	mA
Output diode current	I _{ОК}	(Note 3)	±50	mA
Output current	I _{OUT}		±50	mA
Power dissipation	PD	(Note 4)	180	mW
V _{CC} /ground current	I _{CC}		±100	mA
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state. I_{OUT} absolute maximum rating must be observed.

Note 3: V_{OUT} < GND, V_{OUT} > V_{CC}

Note 4: 180 mW in the range of $T_a = -40$ to 85 °C. From $T_a = 85$ to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

9. Operating Ranges (Note)

Characteristics	Symbol	Note	Test Condition	Rating	Unit
Supply voltage	V _{CC}		—	1.8 to 5.5	V
Input voltage	V _{IN}		—	0 to 5.5	V
Output voltage	V _{OUT}	(Note 1)	—	0 to 5.5	V
		(Note 2)	—	0 to V _{CC}	
Operating temperature	T _{opr}		—	-40 to 125	°C
Input rise and fall times	dt/dv		V_{CC} = 3.3 \pm 0.3 V	0 to 20	ms/V
			V_{CC} = 5.0 \pm 0.5 V	0 to 1	

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either V_{CC} or GND.

Note 1: Output in OFF state.

Note 2: High (H) or Low (L) state.

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10. Electrical Characteristics

10.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
Positive threshold voltage	V _P	_		1.8	_	_	1.65	V
				2.3	_	_	1.85	
				3.0	_	_	2.20	
				4.5	_	—	3.15	
				5.5	_	_	3.85	
Negative threshold voltage	V _N	_		1.8	0.15	—	_	V
				2.3	0.45	_	_	1
				3.0	0.90	_	_	1
				4.5	1.35	_	_	
				5.5	1.65	_	_	1
Hysteresis voltage	V _H	_		1.8	0.15	_	1.05	V
				2.3	0.20	_	1.10	
				3.0	0.30	_	1.20	1
				4.5	0.40	_	1.40	1
				5.5	0.50	_	1.60	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	1.8	1.7	1.8	_	V
				3.0	2.9	3.0	_	
				4.5	4.4	4.5	_	
			I _{OH} = -8 mA	3.0	2.58	_	_	1
			I _{OH} = -16 mA	4.5	3.94	_	_]
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	1.8	_	0.0	0.1	V
				3.0	_	0.0	0.1	1
				4.5	_	0.0	0.1]
			I _{OL} = 8 mA	3.0		_	0.36	
			I _{OL} = 16 mA	4.5	_	_	0.44	1
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 5.5 V		1.8 to 5.5	—	—	±0.5	μA
Power-OFF leakage current	I _{OFF}	V_{IN}/V_{OUT} = 5.5 V		0		—	0.5	μA
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5		_	±0.1	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5		—	2.0	μA

10.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Positive threshold voltage	V _P	—		1.8	_	1.65	V
				2.3	_	1.85]
				3.0	_	2.20]
				4.5	_	3.15]
				5.5	_	3.85	
Negative threshold voltage	V _N	—		1.8	0.15	—	V
				2.3	0.45	—	
				3.0	0.90	—	
				4.5	1.35	_]
				5.5	1.65	_]
Hysteresis voltage	V _H	—		1.8	0.15	1.05	V
				2.3	0.20	1.10]
				3.0	0.30	1.20]
				4.5	0.40	1.40]
				5.5	0.50	1.60	1
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	1.8	1.7	_	V
				3.0	2.9	—]
				4.5	4.4	_]
			I _{OH} = -8 mA	3.0	2.48	—	
			I _{OH} = -16 mA	4.5	3.80	—]
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 50 μA	1.8	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1]
			I _{OL} = 8 mA	3.0	_	0.44]
			I _{OL} = 16 mA	4.5	_	0.55	
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 5.5 V		1.8 to 5.5	_	±5.0	μΑ
Power-OFF leakage current	I _{OFF}	V_{IN}/V_{OUT} = 5.5 V		0	_	5.0	μA
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5		±1.0	μA
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND		5.5	_	20.0	μA

10.3. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Test Conditior	ı	V _{CC} (V)	Min	Max	Unit
Positive threshold voltage	VP	—		1.8	_	1.65	V
				2.3	_	1.85]
				3.0	_	2.20]
				4.5	_	3.15	
				5.5	_	3.85	
Negative threshold voltage	V _N	_		1.8	0.15	—	V
				2.3	0.45	_	
				3.0	0.90	—	
				4.5	1.35	_	
				5.5	1.65	_	
Hysteresis voltage	V _H	—		1.8	0.15	1.05	V
				2.3	0.20	1.10]
				3.0	0.30	1.20	
				4.5	0.40	1.40	
				5.5	0.50	1.60	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -50 μA	1.8	1.7	_	V
				3.0	2.9	—	
				4.5	4.4	—	
			I _{OH} = -8 mA	3.0	2.40	—	
			I _{OH} = -16 mA	4.5	3.70	—	
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 50 μA	1.8		0.1	V
				3.0		0.1	
				4.5		0.1	
			I _{OL} = 8 mA	3.0	_	0.55	
			I _{OL} = 16 mA	4.5	_	0.65	
3-state output OFF-state leakage current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 5.5 V		1.8 to 5.5		±20.0	μA
Power-OFF leakage current	I _{OFF}	V_{IN}/V_{OUT} = 5.5 V		0	_	20.0	μA
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5		±2.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	40.0	μA

10.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	74VHCV240FT	t _{PLH} ,t _{PHL}		—	2.5 ± 0.2	15	_	6.4	11.6	ns
						50	_	9.2	14.4	
					3.3 ± 0.3	15	_	5.0	7.5	
						50	—	7.0	11.0	
					5.0 ± 0.5	15	—	3.9	5.5	
						50	_	5.4	7.5	
Propagation delay time	74VHCV244FT	t _{PLH} ,t _{PHL}		—	2.5 ± 0.2	15	_	6.7	12.5	ns
						50	_	9.5	15.3	
					3.3 ± 0.3	15	_	5.0	8.4	
						50	—	7.2	11.9	
					5.0 ± 0.5	15	_	3.8	5.5	
						50	_	5.4	7.5	
3-state output enable time		t _{PZL} ,t _{PZH}		R _L = 1 kΩ	2.5 ± 0.2	15	_	7.8	14.6	ns
						50	_	11.1	17.8	
					3.3 ± 0.3	15	_	5.7	10.6	
						50	_	8.4	14.1	
					5.0 ± 0.5	15	_	4.1	7.3	
						50	—	6.2	9.3	
3-state output disable time		t _{PLZ} ,t _{PHZ}		$R_L = 1 k\Omega$	2.5 ± 0.2	50	_	14.3	19.2	ns
					3.3 ± 0.3	50	_	10.9	14.0	
					5.0 ± 0.5	50	_	8.7	9.2	
Output skew		t_{osLH}, t_{osHL}	(Note 1)	_	2.5 ± 0.2	50	_	_	2.0	ns
					3.3 ± 0.3	50	_	_	1.5	
					5.0 ± 0.5	50	_	—	1.0	
Input capacitance		C _{IN}		_			_	4	10	pF
Output capacitance		C _{OUT}					_	6	_	pF
Power dissipation	74VHCV240FT	C _{PD}	(Note 2)	_			_	20	_	pF
capacitance	74VHCV244FT	C _{PD}	(Note 2)	_				21	_	pF

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m-t_{PLH}n|$, $t_{osHL} = |t_{PHL}m-t_{PHL}n|$)

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$ (per bit)

10.5. AC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C, Input: t_r = t_f = 3 ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	74VHCV240FT	t _{PLH} ,t _{PHL}		—	2.5 ± 0.2	15	1.0	14.0	ns
						50	1.0	17.0	
					3.3 ± 0.3	15	1.0	9.0	
						50	1.0	12.5	
					5.0 ± 0.5	15	1.0	6.5	
						50	1.0	8.5	
Propagation delay time	74VHCV244FT	t _{PLH} ,t _{PHL}		—	2.5 ± 0.2	15	1.0	15.0	ns
						50	1.0	18.0	
					3.3 ± 0.3	15	1.0	10.0	
						50	1.0	13.5	
					5.0 ± 0.5	15	1.0	6.5	
						50	1.0	8.5	
3-state output enable time		t _{PZL} ,t _{PZH}		$R_L = 1 k\Omega$	2.5 ± 0.2	15	1.0	17.0	ns
						50	1.0	21.0	
					3.3 ± 0.3	15	1.0	12.5	
						50	1.0	16.0	
					5.0 ± 0.5	15	1.0	8.5	
						50	1.0	10.5	
3-state output disable time		t _{PLZ} ,t _{PHZ}		R _L = 1 kΩ	2.5 ± 0.2	50	1.0	21.0	ns
					3.3 ± 0.3	50	1.0	16.0	
					5.0 ± 0.5	50	1.0	10.5	
Output skew		t_{osLH}, t_{osHL}	(Note 1)	_	2.5 ± 0.2	50		2.0	ns
					$\textbf{3.3}\pm\textbf{0.3}$	50	—	1.5	
					5.0 ± 0.5	50	_	1.0	
Input capacitance		C _{IN}		_			_	10	pF

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|$)

10.6. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V _{CC} (V)	$C_L (pF)$	Min	Max	Unit
Propagation delay time	74VHCV240FT	t _{PLH} ,t _{PHL}		—	2.5 ± 0.2	15	1.0	16.0	ns
						50	1.0	19.0	
					$\textbf{3.3}\pm\textbf{0.3}$	15	1.0	10.5	
						50	1.0	14.0	
					5.0 ± 0.5	15	1.0	7.5	
						50	1.0	9.5	
Propagation delay time	74VHCV244FT	t _{PLH} ,t _{PHL}		—	2.5 ± 0.2	15	1.0	17.0	ns
						50	1.0	20.0	
					$\boxed{3.3\pm0.3}$	15	1.0	11.5	
						50	1.0	15.0	
					5.0 ± 0.5	15	1.0	7.5	
						50	1.0	9.5	
3-state output enable time		t _{PZL} ,t _{PZH}		$R_L = 1 k\Omega$	2.5 ± 0.2	15	1.0	19.0	ns
						50	1.0	23.5	
					$\boxed{3.3\pm0.3}$	15	1.0	14.5	
						50	1.0	18.0	
					5.0 ± 0.5	15	1.0	10.0	
						50	1.0	12.0	
3-state output disable time		t _{PLZ} ,t _{PHZ}		$R_L = 1 k\Omega$	2.5 ± 0.2	50	1.0	22.5	ns
					$\textbf{3.3}\pm\textbf{0.3}$	50	1.0	17.5	
					5.0 ± 0.5	50	1.0	11.5	
Output skew		t_{osLH}, t_{osHL}	(Note 1)	_	2.5 ± 0.2	50		2.0	ns
					$\textbf{3.3}\pm\textbf{0.3}$	50		1.5	
					5.0 ± 0.5	50		1.0	
Input capacitance		C _{IN}		_			_	10	pF

Note 1: Parameter guaranteed by design. ($t_{osLH} = |t_{PLH}m-t_{PLH}n|$, $t_{osHL} = |t_{PHL}m-t_{PHL}n|$)

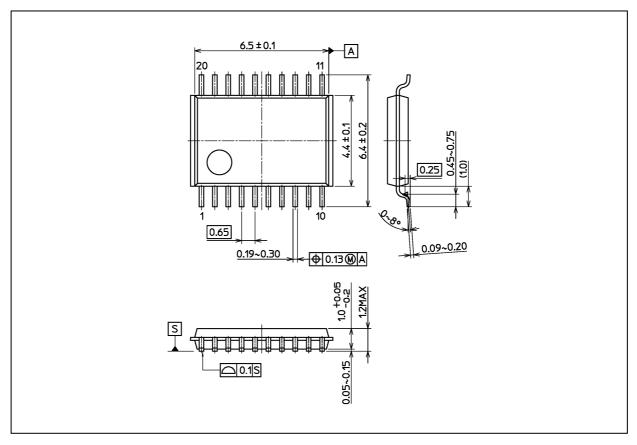
10.7. Noise Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V_{OL}	V _{OLP}	C _L = 50 pF	3.3	0.45	—	V
			5.0	0.9	—	
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	3.3	-0.1	—	V
			5.0	-0.3	—	
Minimum high-level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	_	3.5	V
Maximum low-level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0	_	1.5	V



Package Dimensions

Unit: mm



Weight: 0.071 g (typ.)

	Package Name(s)
Nickname: TSSOP20B	

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